

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
60V	5Ω@10V	0.1A
	8Ω@4.5V	

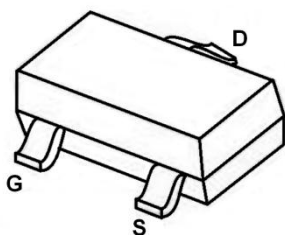
Feature

- High power and current handling capability
- Surface mount package
- ESD protected

Application

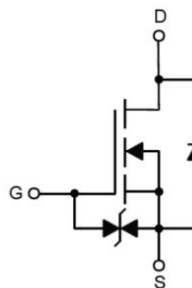
- Battery Switch
- DC/DC Converter

Package

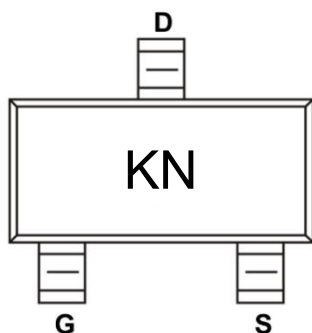


SOT-323

Circuit diagram



Marking



Absolute maximum ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	0.1	A
Pulsed Drain Current	I_{DM}	0.4	A
Power Dissipation	P_D	0.3	W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	416	$^{\circ}\text{C/W}$
Operating Junction Temperature	T_J	$-55 \sim +150$	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

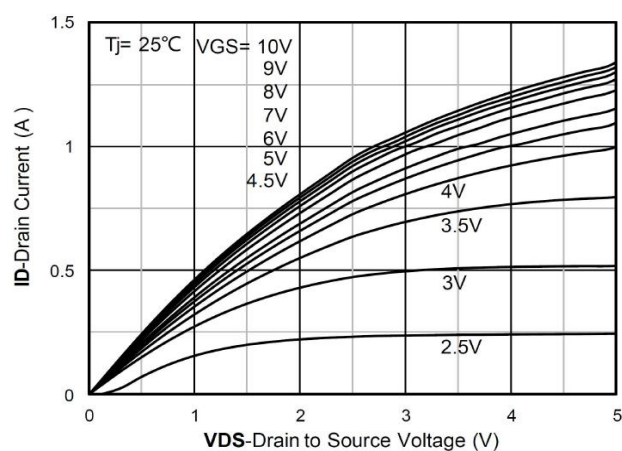
Electrical characteristics ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static characteristics						
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Zero Gate voltage drain current	I_{DSS}	$V_{DS}=48V, V_{GS}=0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 10	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.7	2	1.45	V
Drain-Source on-resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=0.2A$		2	5	Ω
		$V_{GS}=4.5V, I_D=0.1A$		2.5	8	
Dynamic characteristics ¹⁾						
Input capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1MHz$		12		pF
Output capacitance	C_{oss}			6		
Reverse transfer capacitance	C_{rss}			2.5		
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=15V, I_D=1A$		1.34		nC
Gate-Source Charge	Q_{gs}			0.29		
Gate-Drain Charge	Q_{gd}			0.2		
Turn-on delay time	$t_{d(on)}$	$V_{DS}=15V, V_{GS}=10V, I_D=1A$ $R_G=2.3\Omega$		5		nS
Turn-on rise time	t_r			18		
Turn-off delay time	$t_{d(off)}$			8		
Turn-off fall time	t_f			14		
Source-Drain Diode characteristics						
Diode Forward Current	I_S				0.1	A
Diode forward voltage	V_{SD}	$V_{GS}=0V, I_S=1A, T_J=25^{\circ}C$			1.2	V

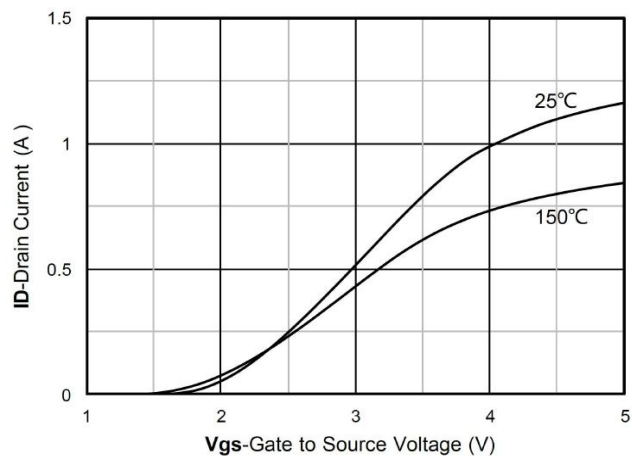
Notes:

1) Guaranteed by design, not subject to production testing.

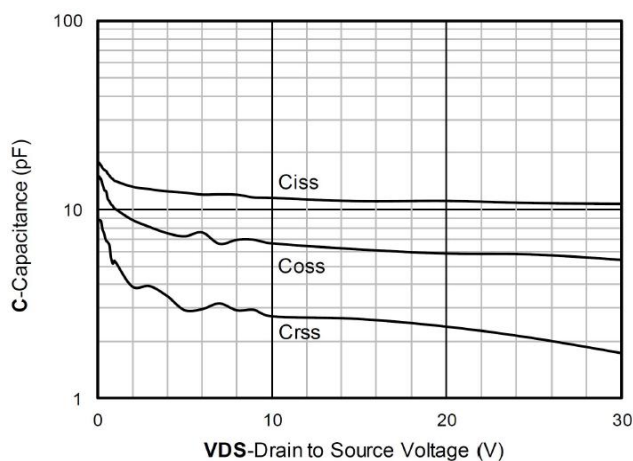
Typical Characteristics



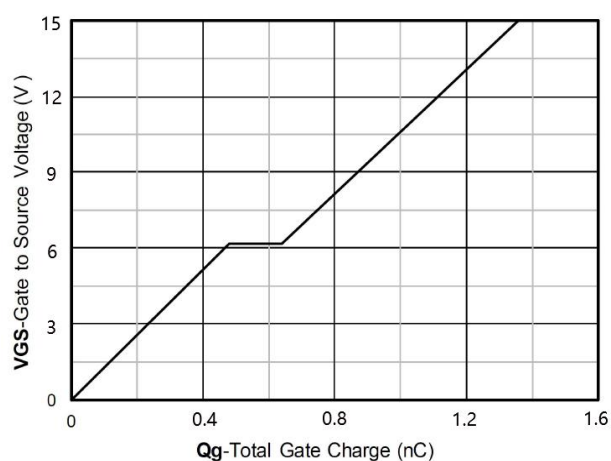
Output Characteristics



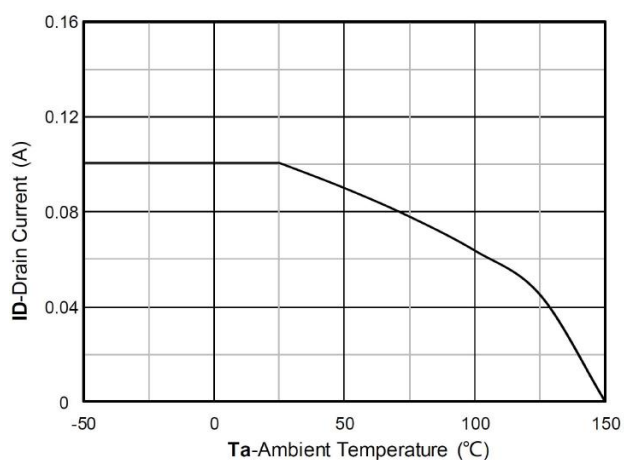
Transfer Characteristics



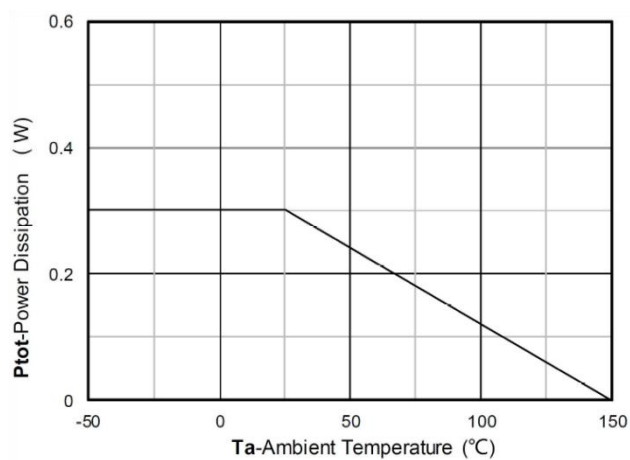
Capacitance Characteristics



Gate Charge

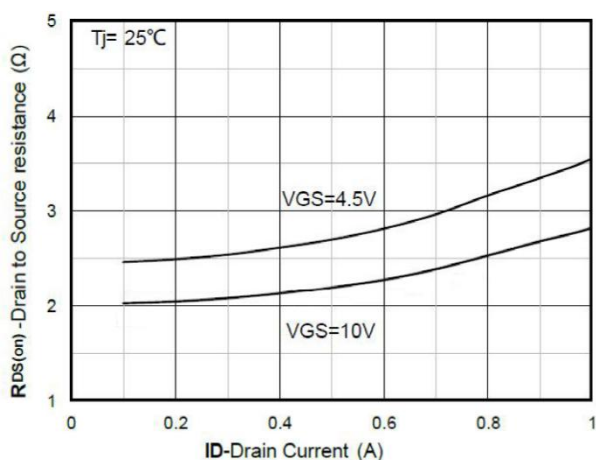


Current dissipation

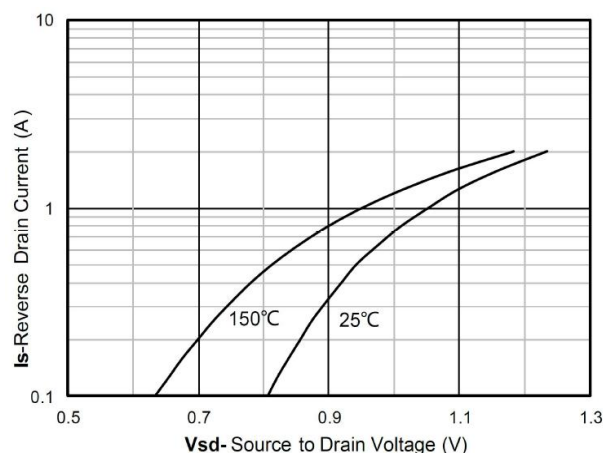


Power dissipation

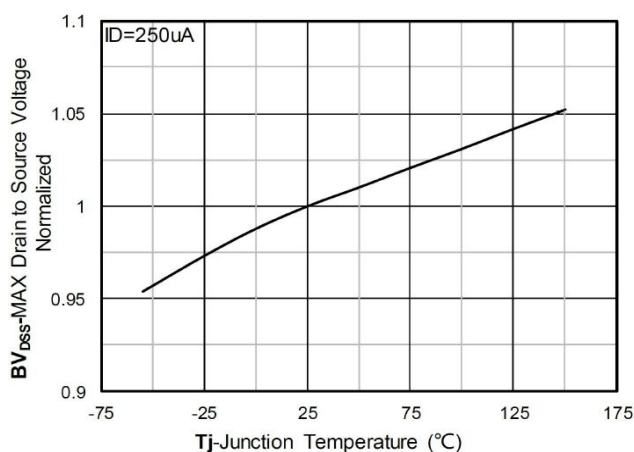
Typical Characteristics



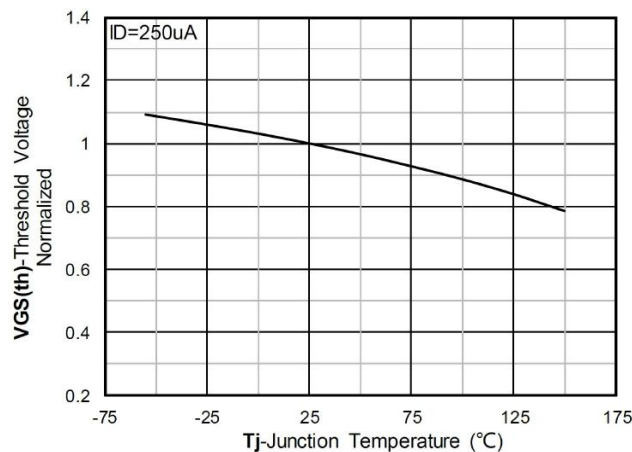
$R_{DS(on)}$ VS Drain Current



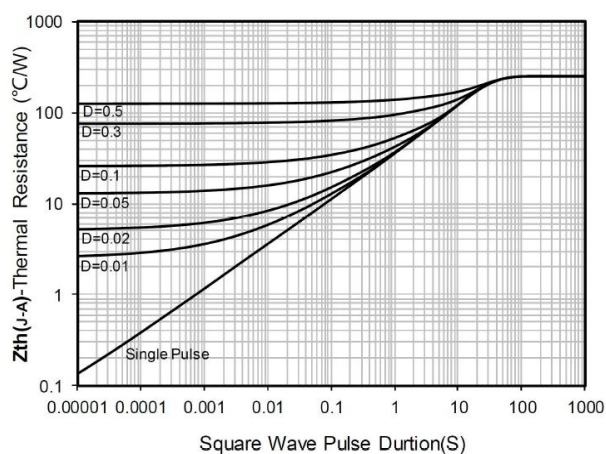
Forward characteristics of reverse diode



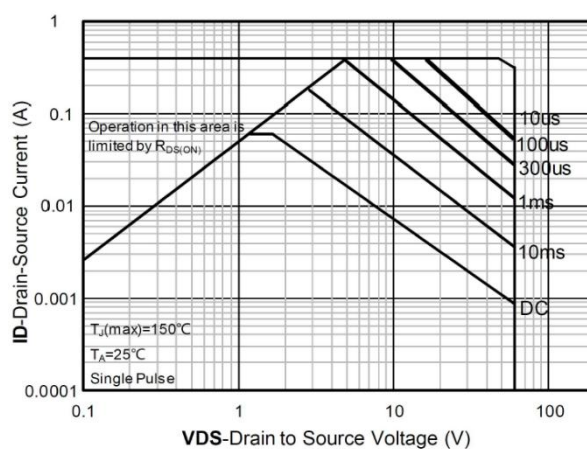
Normalized breakdown voltage



Normalized Threshold voltage

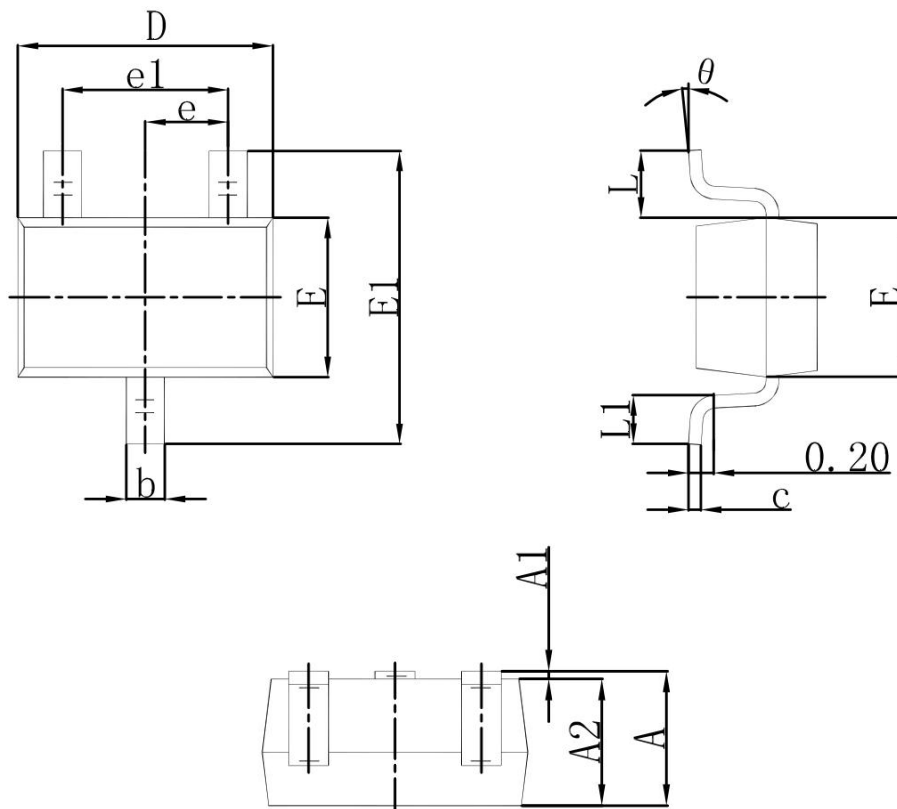


Maximum Transient Thermal Impedance



Safe Operation Area

SOT-323 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.000	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.250	0.460	0.010	0.018
θ	0°	8°	0°	8°